

Description

The 2N7002T uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

 $V_{DS} = 60V I_D = 0.115A$ $R_{DS(ON)} < 3 \Omega @ V_{GS} = 10V$ ESD Rating: HBM $\ge 2000V$

Application

Battery protection Load switch Uninterruptible power supply

Package Marking and Ordering Information

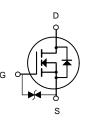
Product ID	Pack	Marking	Qty(PCS)
2N7002T	SOT-523		3000

Absolute Maximum Ratings (T_A=25[°]C unless otherwise noted)

Symbol	ol Parameter		Unit	
VDS	Drain-Source Voltage	60	V	
Vgs	Gate-Source Voltage	±20	V	
١D	Drain Current-Continuous	0.115	A	
PD	Maximum Power Dissipation	0.15	W	
Tj,Tstg	Digitize Coperating Junction and Storage Temperature Range		°C	
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)	833	°C/W	







N-Channel MOSFET



Electrical Characteristics (TJ=25 °C, unless otherwise noted)

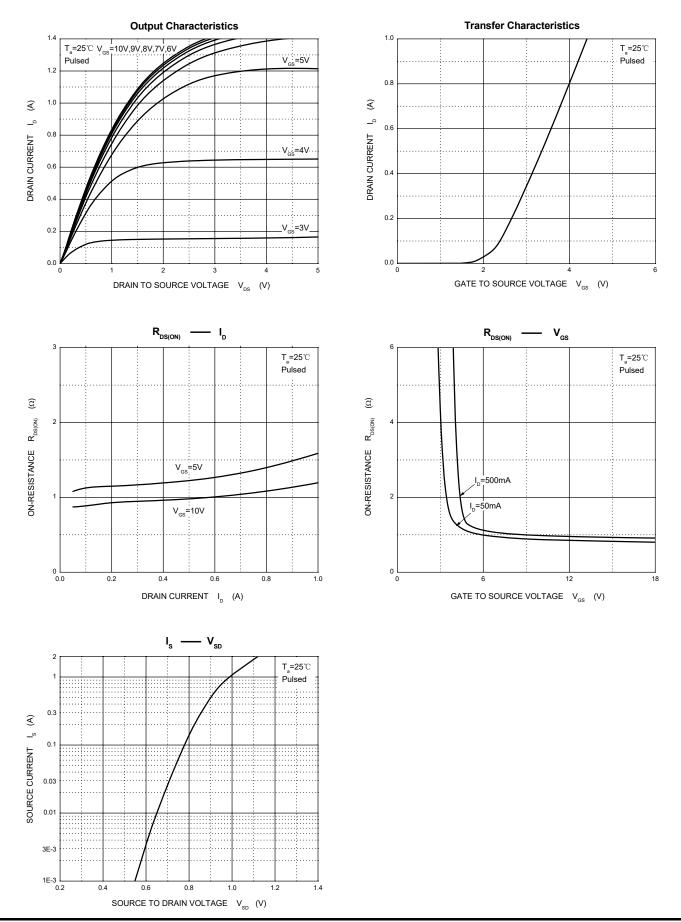
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0 V, I _D =250 μA	60			V	
Gate-Threshold Voltage	V _{th(GS)}	V _{DS} =V _{GS} , I _D =250 μA	1		2.5		
Gate-body Leakage	I _{GSS}	V _{DS} =0 V, V _{GS} =±20 V			±80	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60 V, V _{GS} =0 V			80	nA	
On-state Drain Current	I _{D(ON)}	V _{GS} =10 V, V _{DS} =7 V	500			mA	
Durin Original On Desistance		V _{GS} =10 V, I _D =115mA		1.3	3	Ω	
Drain-Source On-Resistance	$R_{DS(on)}$	V _{GS} =4.5V, I _D =50mA		2	5		
Forward Trans conductance	g _{fs}	V _{DS} =10 V, I _D =200mA	80			ms	
D		V _{GS} =10V, I _D =500mA			3.75	V	
Drain-source on-voltage	V _{DS(on)}	V _{GS} =5V, I _D =50mA			0.375	V	
Diode Forward Voltage	V _{SD}	I _S =115mA, V _{GS} =0 V	0.55		1.2	V	
Input Capacitance	C _{iss}				50		
Output Capacitance	C _{oss}	V _{DS} =25V, V _{GS} =0V, f=1MHz			25	pF	
Reverse Transfer Capacitance	C _{rss}				5		
SWITCHING TIME	I	1	I	1	1	1	
Turn on Time	t	V _{DD} =25 V. R _I =50Ω					

Turn-on Time	t _{d(on)}	$V_{DD}=25 \text{ V}, \text{ R}_{L}=50\Omega$		20	20	
Turn-off Time	$t_{d(off)}$	I _D =500mA,V _{GEN} =10 V R _G =25 Ω		40	ns	



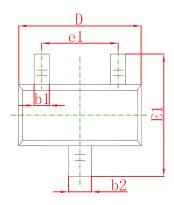
2N7002T N-Channel Enhancement Mode MOSFET

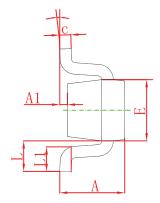
Typical Characteristics





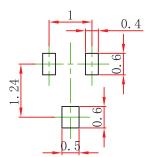
SOT-523 Package Information





Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	0.700	0.900	0.028	0.035	
A1	0.000	0.100	0.000	0.004	
A2	0.700	0.800	0.028	0.031	
b1	0.150	0.250	0.006	0.010	
b2	0.250	0.350	0.010	0.014	
С	0.100	0.200	0.004	0.008	
D	1.500	1.700	0.059	0.067	
E	0.700	0.900	0.028	0.035	
E1	1.450	1.750	0.057	0.069	
е	0.500 TYP.		0.020 TYP.		
e1	0.900	1.100	0.035	0.043	
L	0.400 REF.		0.016 REF.		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

SOT-523 Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:±0.05mm.

3. The pad layout is for reference purposes only.



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